



立百邑有限公司

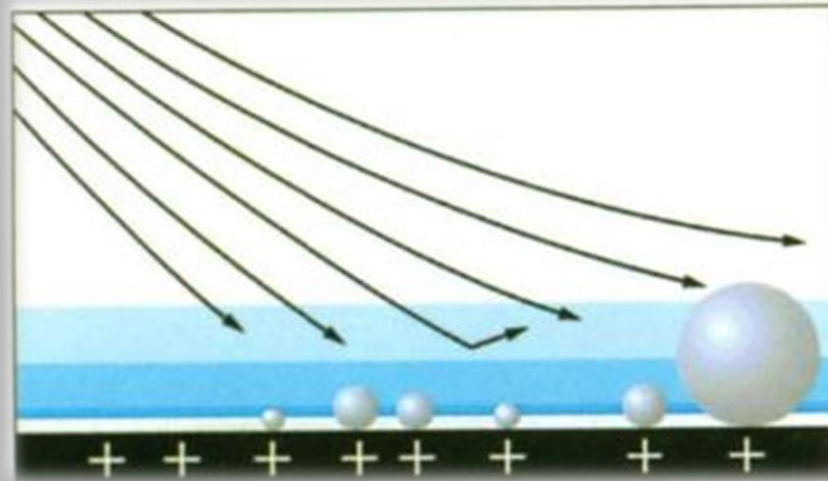
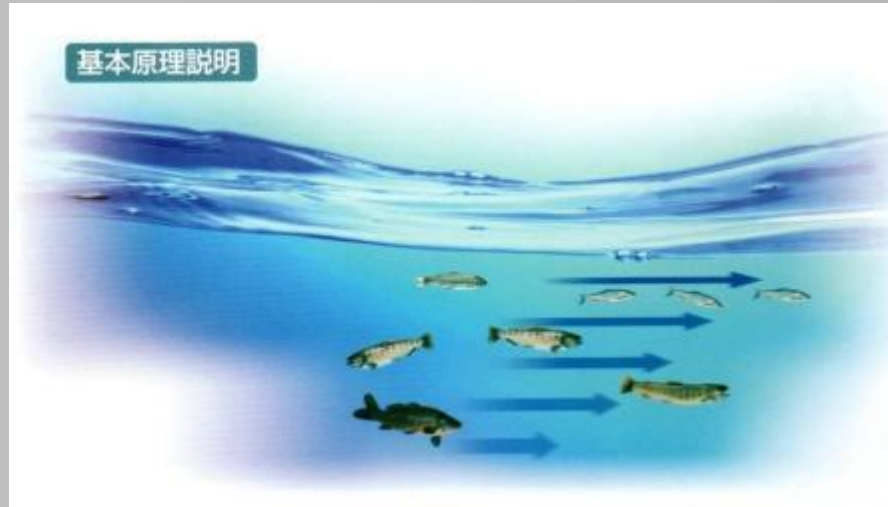
LiBaiYi Co., Ltd.

乾式超聲波清潔
Dry Ultrasonic Clean 簡介



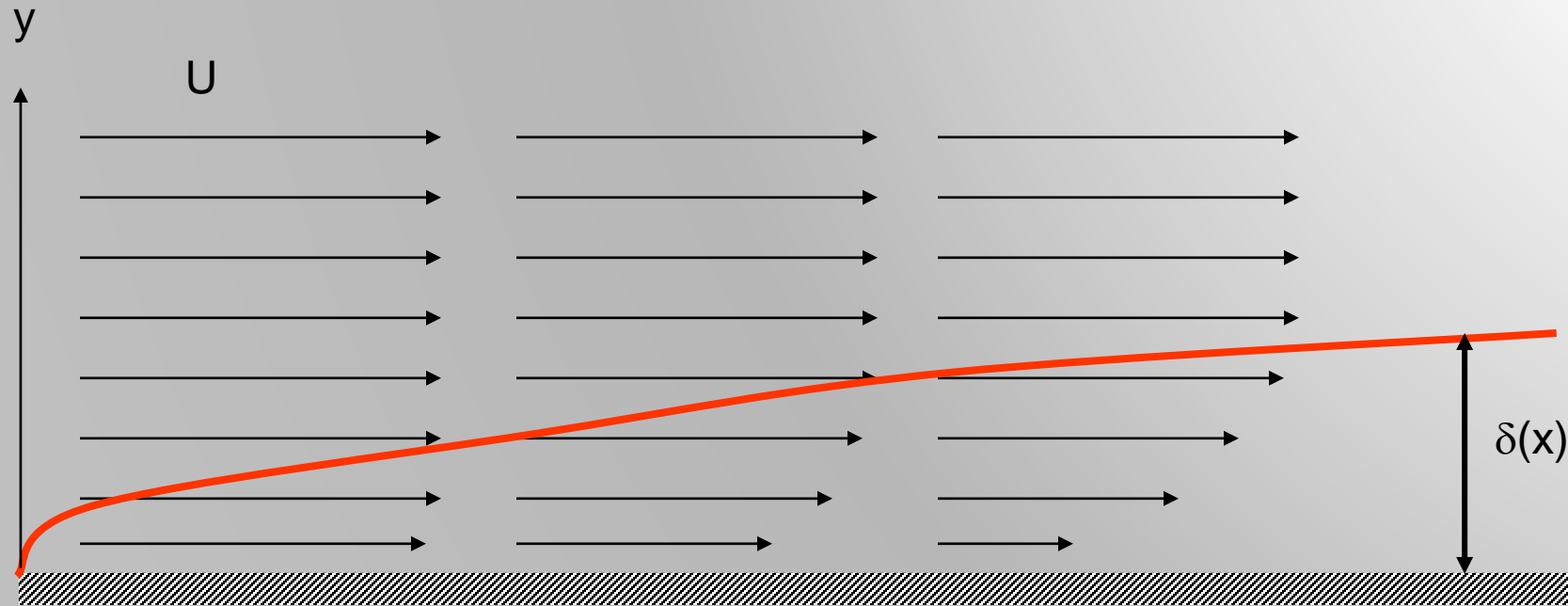
為何要使用超聲波清潔？

流體邊界層效應



氣體於固體表面上流動，不管流速多快，於固體表面一定會有一流速緩慢的層流層(Laminar flow)，就像海洋，海水表面波濤洶湧，但海面底下的魚不受影響。此流速緩慢的層流層使小顆粒particle ($<20\mu\text{m}$) 無法有效被去除。

邊界層厚度(Boundary layer thickness)



U is the free-stream velocity

$\delta(x)$ is the boundary layer thickness when $u(y) = 0.99U$

清潔設備的演進與趨勢



Wet Cleaning

- Remove of oil and particle
- Enhance bonding yield
- A large amount of solvent
- Environment pollution
- Solvent residue



- In line process
- High through put



Dry Atmospheric Cleaning

AP Plasma Cleaning

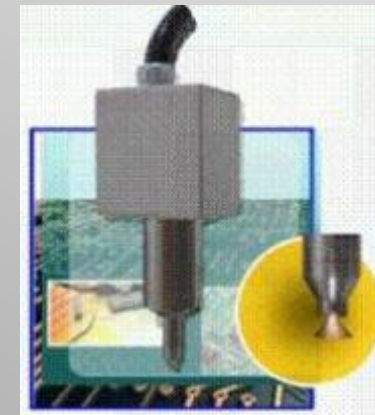
Dry Ultrasonic Cleaning

- In-Line processes
- Low cost
- Low running cost
- No limits of surface area
- Cost-effective process
- Large area
- High cleaning speed



Plasma Dry Cleaning

- Reduce need for toxic solvents
- Reduced environmental pollution
- Reduced worker exposure
- Safe end products
- Cost-effective process
- Vacuum environment
- High cost



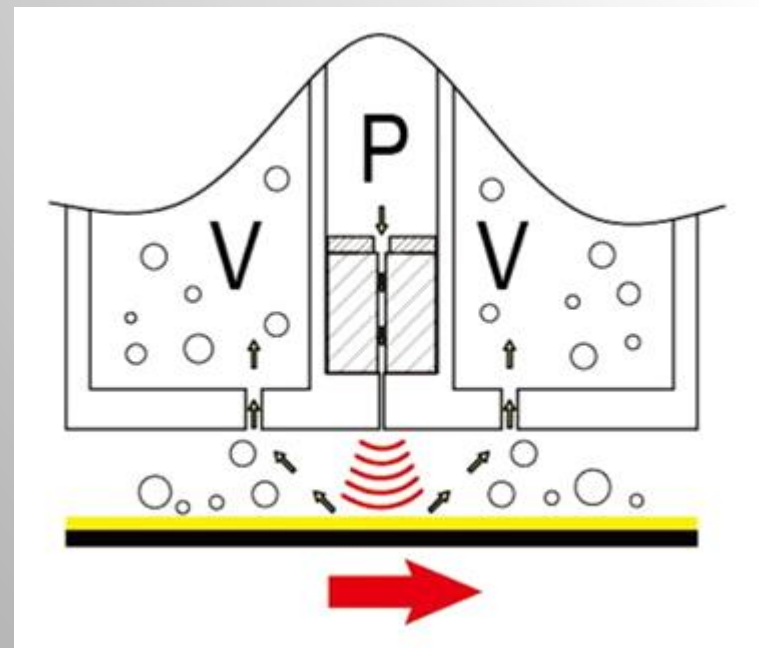
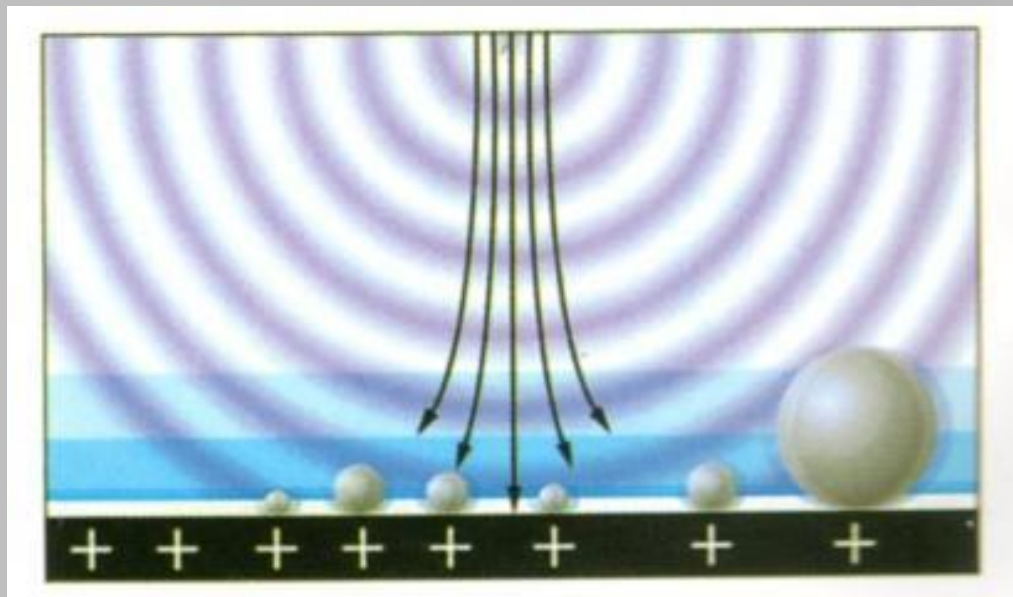
Particle 污染機制



※試片因環境在製程及運送過程，產生粉塵污染，造成後續製程良率不佳

常見的污染機制可細分為6大類，
(1)~(4)可用DUC去除
(3)~(5)可用AP Plasma去除
(6)僅能使用相對應化學品去除

Dry Ultrasonic Clean 原理說明



超聲波清潔的原理是藉由超聲波突破邊界層，將振動能量傳遞至粉塵，進而與基板分離後，由兩側的排氣口吸除

Dry Ultrasonic Clean 實體照片與介紹

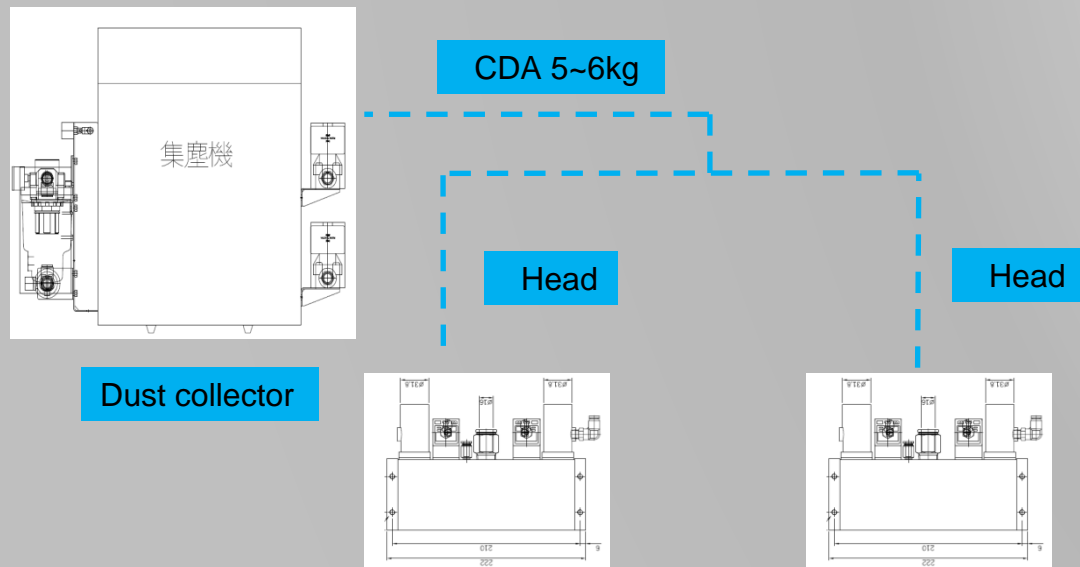


- 3um particle 去除率高達98%以上。(on glass)
- 免維修、低損耗、空間易配置。
- 氣流平衡設計，Particle不外流
- 採用 VPV / PV超音波高壓振盪風刀，以具超音波效能之強力風刀，去除物件邊界層之Particle，再由兩側高壓集塵，產生真空效應清除粉塵
- 非接觸式除塵，無損傷材質疑慮。
- 搭配日本集塵機及高效過濾設備，品質穩定，並達到極高標準之清潔效果
- 超音波Head達到業界最薄**50mm**，並可配合客戶設備空間，客製化設計。

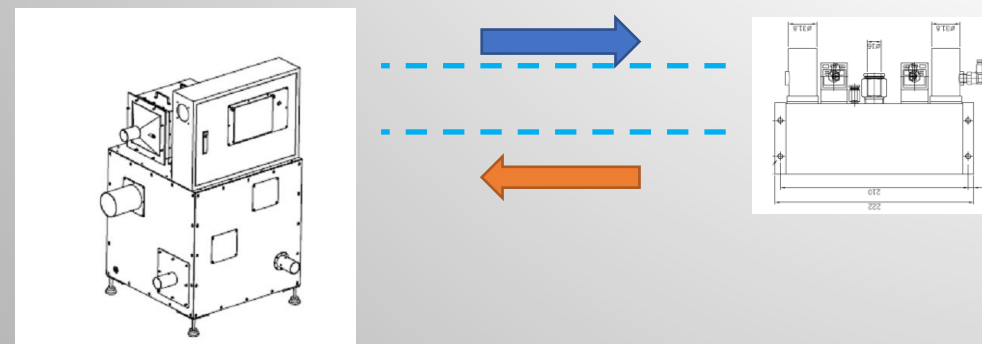


Dry Ultrasonic Clean 架構說明

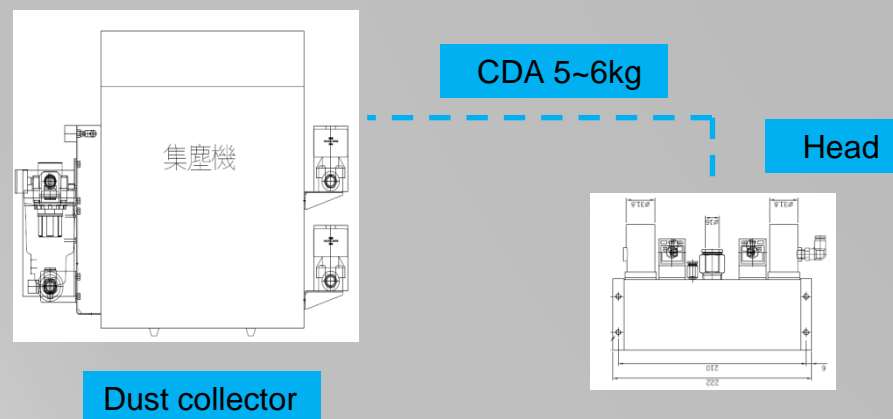
CDA TYPE 1對2(適用無塵室)



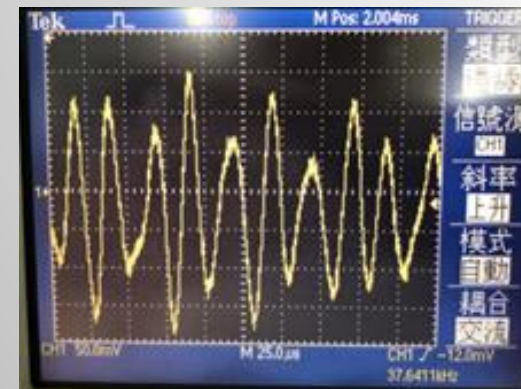
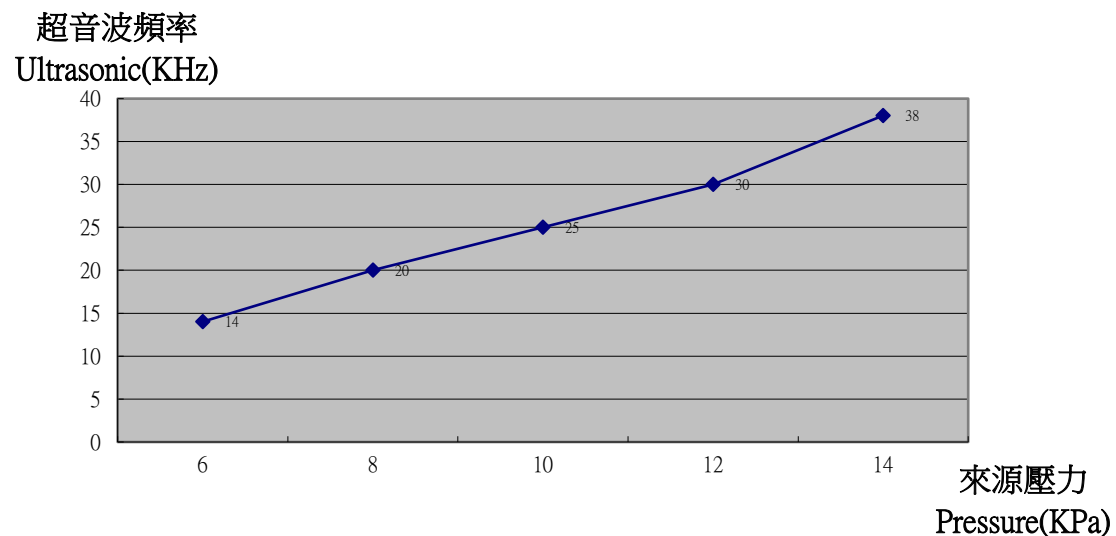
Blower TYPE 1對1



CDA TYPE 1對1(適用無塵室)



Dry Ultrasonic Clean 壓力與頻率



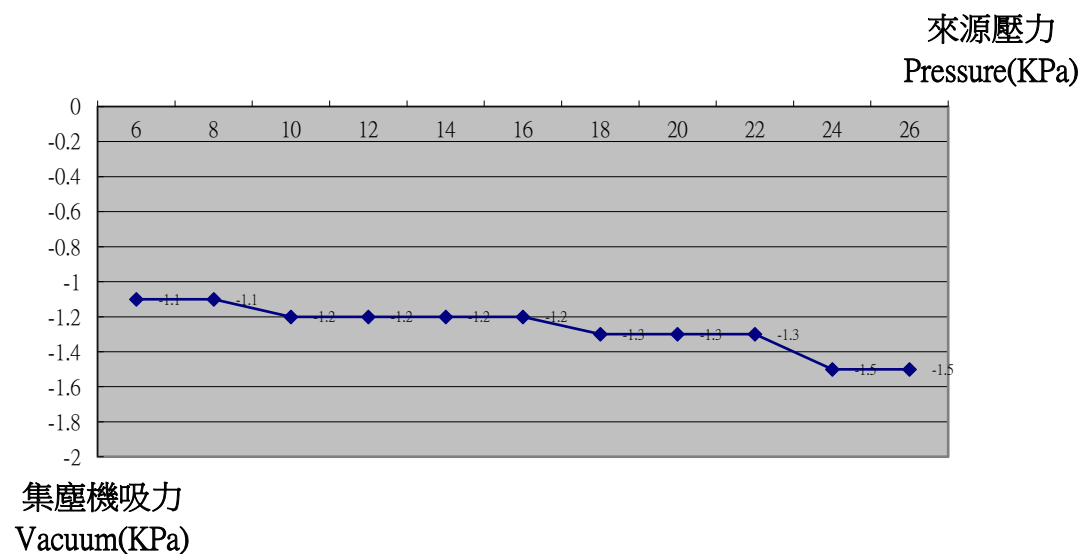
測試參數：

型號：DUC-300C

Head尺寸(有效寬度)：300mm

Head至產品高度(gap)：2mm

集塵機品牌：CHIKO (JP)



Dry Ultrasonic Clean 測試報告



Test 1 Al at 2mm GAP on glass

No.	1 (98.98%)	2 (98.78%)	3 (99.22%)	4 (98.46%)	5 (98.11%)
USC 前 (ea)	0	0	0	0	0.1
异物 涂布 (ea)	138	164	3240	98	106
USC 后 (ea)	1.4	2	< 25	1.5	2.1

Test 2 SiO2 at 2mm GAP on glass

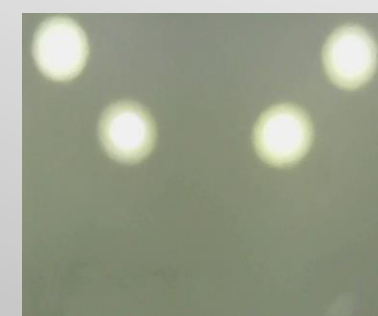
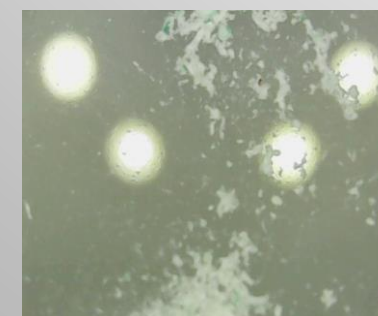
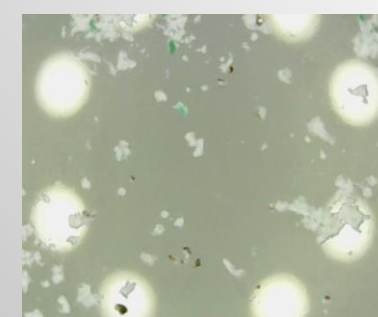
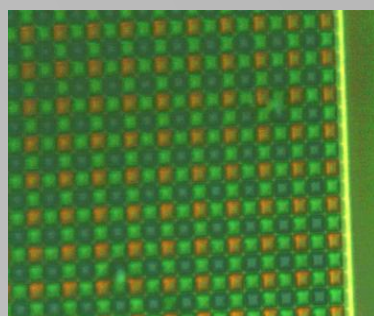
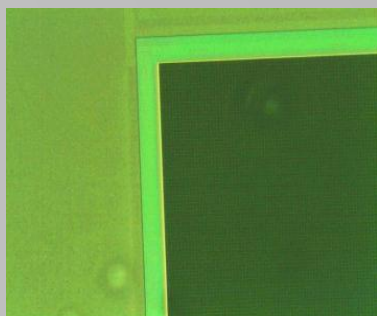
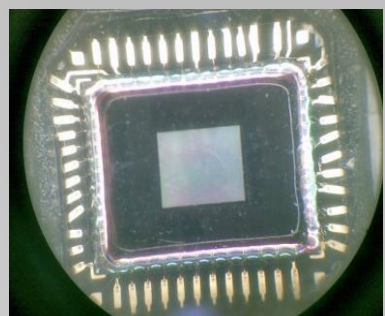
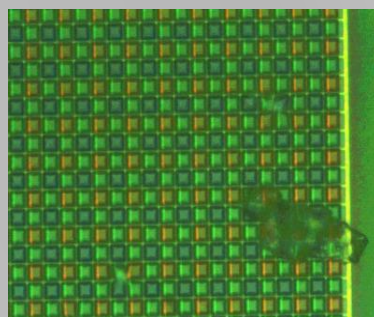
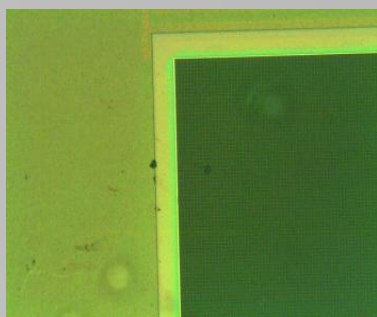
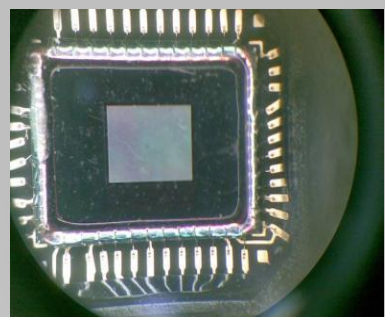
No.	1 (99.80%)	2 (99.81%)	3 (99.61%)	4 (99.92%)	5 (99.92%)
USC 前 (ea)	0	0	0	0	0
异物 涂布 (ea)	518	323	1296	241	324
USC 后 (ea)	1.0	0.6	< 5	0.2	0.2

Dry Ultrasonic Clean 測試報告



Test 3 SiO₂ at 2mm GAP on CMOS
※Clean and no Damage

Test 4 SiO₂ at 2mm GAP on Lens



DUC Clean (60X)

DUC clean (100X)

DUC Clean (500X)

Before Particle

After Particle

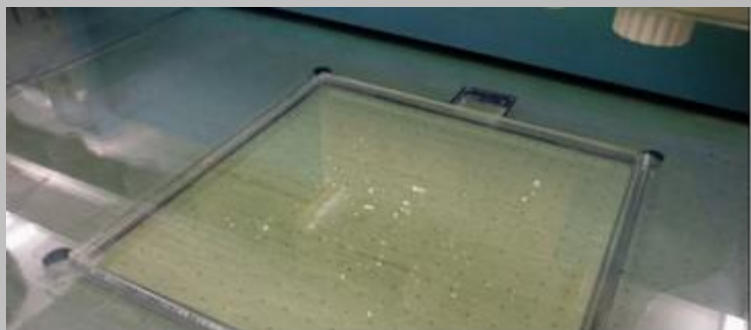
After DUC

Dry Ultrasonic Clean 測試報告



Test 5 Wafer Mask Clean

※High Light Detection, 3um Particle(no adhesion) 99% Clean



Before Particle



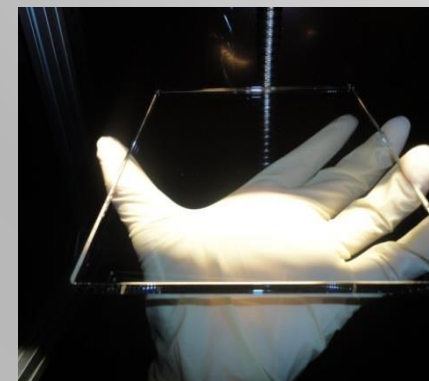
DUC clean



After DUC



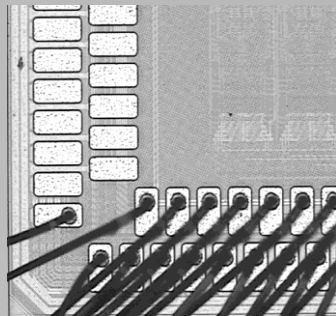
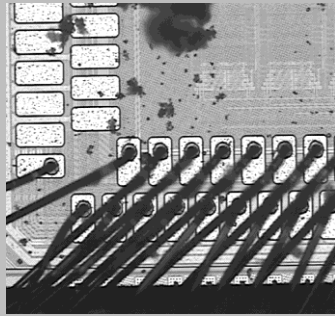
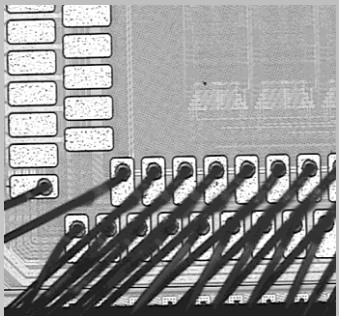
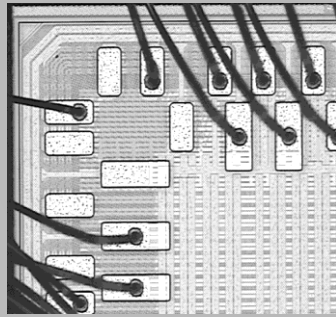
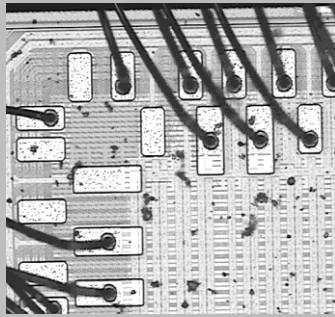
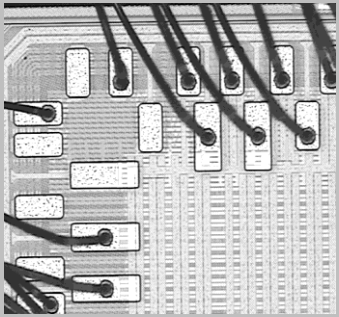
High Light detection



After Clean



Test 6 SiO₂ at 2mm GAP on Lead Frame
※10um Particle 85% Clean + and No Wire Sag



Before Particle

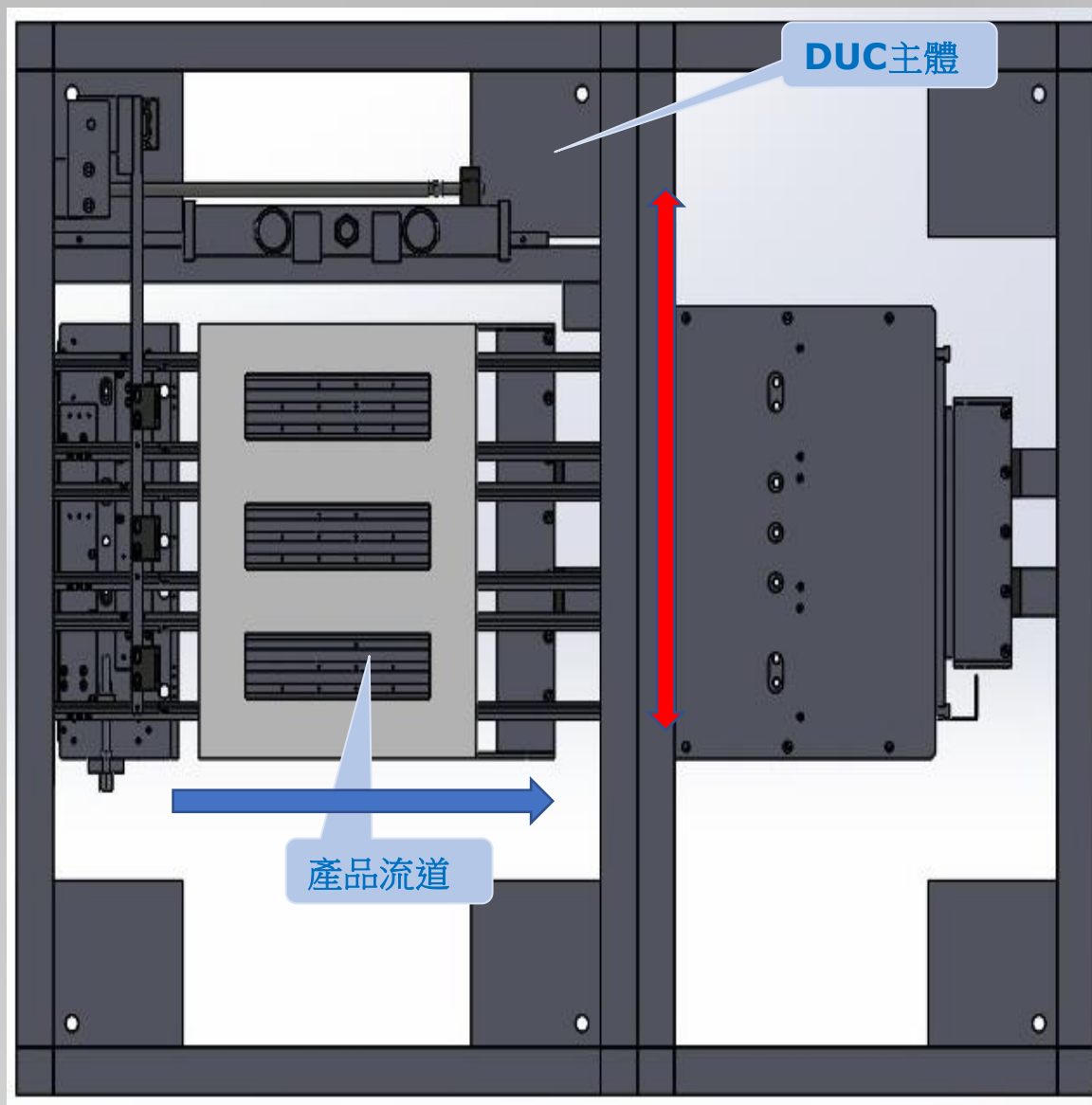
After Particle

After DUC



No Wire sag

Dry Ultrasonic Clean 架設範例 (Plasma後)





Dry Ultrasonic Clean 測試報告

Dry Ultrasonic Clean test (5kg 壓力吹出)

Particle size	Particle count (as is)	Particle count (to be)
>80	5	0
>70	2	0
>60	15	0
>50	22	0
>40	16	2
>30	55	6
>20	168	15
>10	292	23
Total	575	78
Clear rate %	92%	

Air shower test (5kg 壓力吹出)

Particle size	Particle count (as is)	Particle count (to be)
>80	8	0
>70	5	1
>60	10	0
>50	16	6
>40	11	6
>30	43	35
>20	124	85
>10	268	142
Total	485	78
Clear rate %	44.3%	

DOE Base 4x13 BGA dummy die test result / 風壓條件 5kg

Air shower 吹除效果與 DUC 清潔效果可看出模組功能清潔效益 (以40um 以下最為明顯)

DOE 範本

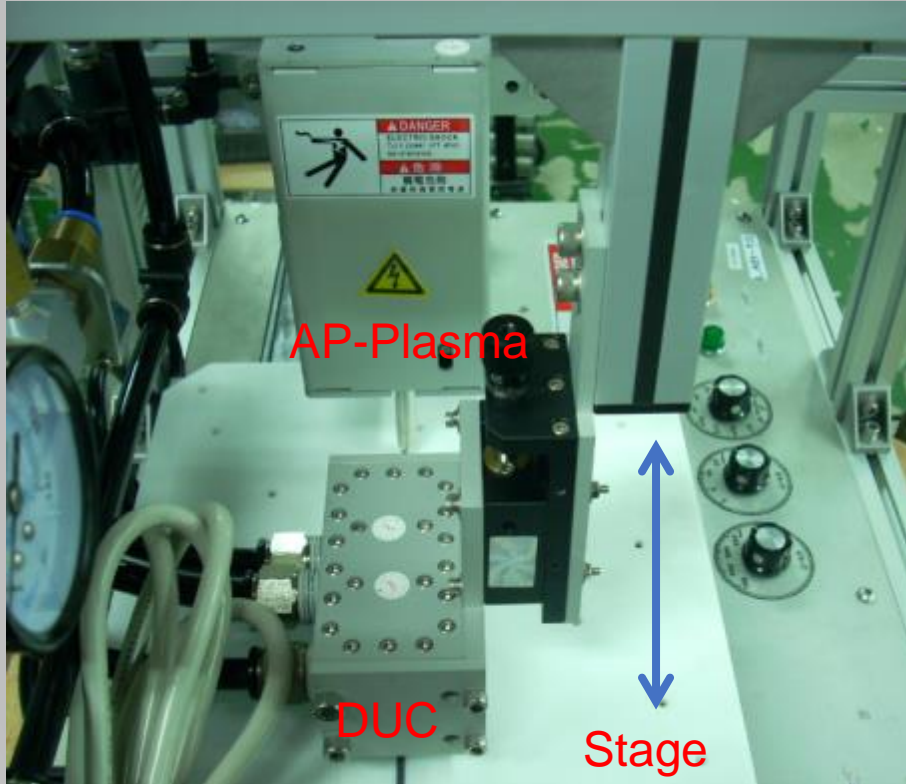


LOT NO	25XXXX-B001
Package Type	
Device Name	
Lot size	
Lot start time	
Lot completed time	

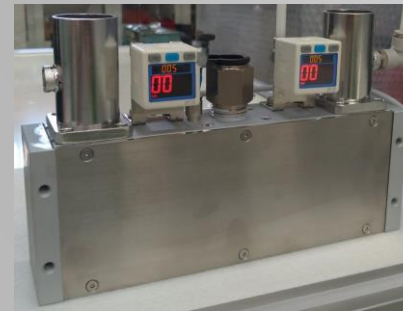
									1
									2
									3
									4

Particle size	Particle count (as is)	Particle count (to be)
>80		
>70		
>60		
>50		
>40		
>30		
>20		
>10		
Total		
Clear rate %		

Dry Clean System原理說明 (Dry Ultrasonic Clean and Atmospheric Plasma)



AP-Plasma



DUC system

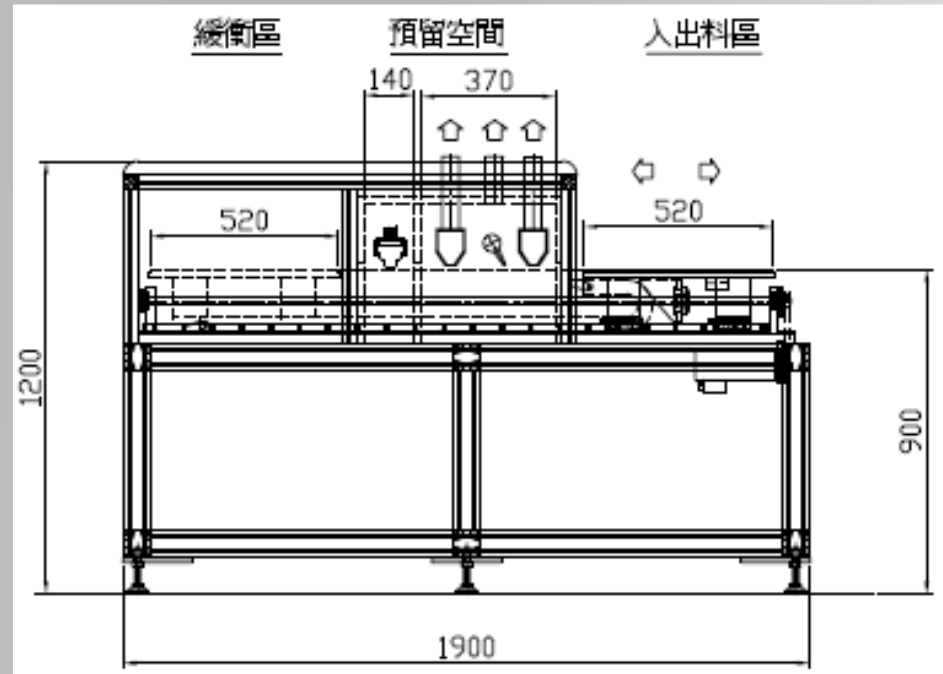


整合DUC及AP-Plasma進行非接觸式清潔的單機系統，可支援UD/LUD，達至非接觸式完全清潔，將頑固的Particle及Organic Pollutant單機清潔完畢

Dry Clean System實績案例 (Dry Ultrasonic Clean and Atmospheric Plasma)



**AP-Plasma + DUC system
off-line/in-line solution**



整合DUC及AP-Plasma進行非接觸式清潔的單機系統，可支援UD/LUD，達至非接觸式完全清潔，將頑固的Particle及Organic Pollutant單機清潔完畢

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可成科技



COMPAL

SunVin
三赢兴科技



KURODA GROUP



Thank You For Listening

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